N on-invasive detection of charge-rearrangement in a quantum dot in high magnetic elds

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(D ated: M arch 23, 2024)

We demonstrate electron redistribution caused by magnetic eld on a single quantum dot measured by means of a quantum point contact as non-invasive detector. Our device which is fabricated by local anodic oxidation allows to control independently the quantum point contact and all tunnelling barriers of the quantum dot. Thus we are able to measure both the change of the quantum dot charge and also changes of the electron con guration at constant number of electrons on the quantum dot. We use these features to exploit the quantum dot in a high magnetic eld where transport through the quantum dot displays the elects of Landau shells and spin blockade. We con rm the internal rearrangement of electrons as function of the magnetic eld for a xed number of electrons on the quantum dot.

PACS num bers: 73.63 Kv, 73.23 Hk, 72.20 My

Soon after their rst realization quantum dots were seen as a model system for the study of the inner structure of a few electron system [1]. They were often called articial atoms in relation to their natural counterpart. Electronic transport through the dots allowed for quite a sophisticated investigation of e.g. the shell structure of few electron dots [2]. But changes of the internal structure i.e. a charge redistribution without changes of the electron number are rather dicult to access.

The most recent interest in quantum dots stems from the goal of realizing quantum bits (qubits) in a sem iconductor structure. Readout schemes for these qubits require non-invasive methods of charge and spin detection β]. Here quantum point contacts (QPC) can be used to detect individual tunneling events of electrons out of the quantum dot (QD) or between the dots of a double dot system [4, 5, 6, 7, 8].

Here we will demonstrate that the QPC can also be used to detect changes of the electron con guration of a QD without changing the number of electrons. Our interest focuses on a QD in a high magnetic eld. Transport m easurements through a QD in this regime display an interesting behavior of the chemical potential of the QD and the tunneling am plitudes which were interpreted by M cEuen et al in a framework of Landau shells [9]. Here we will give direct evidence of the redistribution of charge on the QD within the Coulomb blockade regime which con im s the interpretation of M cEuen et al.

O ur device is based on a G aA s/A G aA s heterostructure containing a two-dimensional electron system (2D E S) 34 nm below the surface. The electron density is $n = 4.59 \ 10^{15} \text{ m}^2$, the mobility is $= 64.3 \ \text{m}^2 = \text{V s. W} \text{ e}$ use an atom ic force m icroscope (AFM) to de ne the QD and the QPC structure by local anodic oxidation (LAO) [10, 11, 12]. In this way the 2D ES below the oxidized surface is depleted and insulating areas can be written. An AFM in age of our device is presented in the inset of Fig. 1. The bright walls depict the insulating lines written by the AFM. The QPC (left area) is separated from the QD structure (right area) by an insulating line. The QPC can be tuned using the in-plane gate G3. The QD is coupled to source and drain via two tunnelling barriers, which can be separately controlled with gates G1 and G2. These gates are also used to control the number of electrons in the QD. We use two electrically separated circuits to perform independent conductance m easurem ents through the QPC and the QD at the sam e tim e. All m easurem ents are done in a ${}^{3}\text{He}/{}^{4}\text{He}$ dilution refrigerator at a base tem perature of 40 m K. In Fig. 1

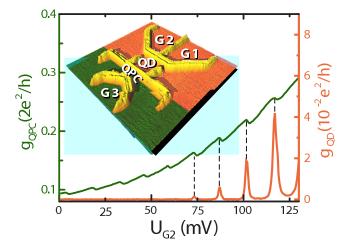


FIG.1: Operating principle of the device containing a QD and a QPC.Conductivity of QD (lower line, right axis) and QPC (upper line, left axis) are shown as a function of gate voltage applied to G2. The inset shows a three-dimensional AFM in age of the device.

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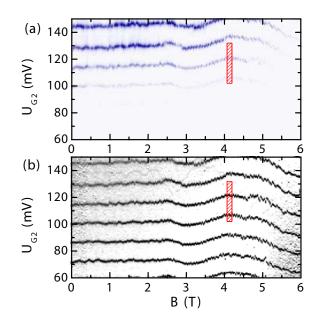


FIG. 2: (a) Conductance $g_{Q\,D}$ of the QD and (b) $dg_{Q\,PC} = dU_{G\,2}$ of the QPC as a function of gate voltage and m agnetic eld, where light-colored m eans zero conductance and dark nite conductance. Several C oulom b peaks can be seen, changing the position with increasing magnetic eld. Even for vanishing transport through the QD the QPC signal clearly traces the addition of further electrons to the QD. The hatched boxes represent the m easurem ent range shown in Fig. 3.

the conductance of the QD and the QPC is shown as a function of the gate voltage applied to gate G2. The conductivity of the QD (low er line) displays typical C oulom b blockade peaks: W henever a state in the QD comes into resonance with the leads, a nonzero conductance through the QD occurs. At the same time a step appears in the QPC conductance (upper line) due to the charge of the additional electron on the QD. The steps are superim – posed on a gradual rise of the conductance caused by the direct in uence of G2 on the QPC potential. Due to its high sensitivity the QPC is an excellent probe for charge redistributions on the QD.

W e studied the conductance of the QD and the QPC in dependence of a magnetic eld applied perpendicular to the plane of the 2DES. Figure 2 gives an overview up to 6 T. In Fig. 2(a) the conductance of the QD is shown as a function of gate voltage applied to G2 and magnetic eld, where white means zero and darker color

nite conductance. In the depicted range of gate voltage one can see four darker lines, that represent the C oulom b blockade peaks. The peak positions slightly change with varying magnetic eld. This is a result of a change in the Ferm i energy of the leads. Between 3 and 5 T the lines show a small zigzag pattern. As there is no transport through the QD between two C oulom b peaks the conductance between the lines is zero. Figure 2 (b) show s the simultaneously measured QPC signal. We have plotted the derivative of the QPC conductance with respect

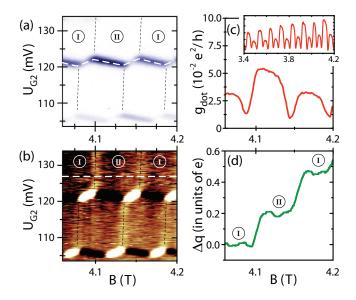


FIG.3: (a) Conductance of the QD as a function of gate voltage and magnetic eld in more detail. The Coulom b peaks show a typical zigzag pattern as a function of magnetic eld. (b) Same range of B for $dg_{QPC} = dB$. Vertical dashed lines drawn are guides to the eye. Between the Coulom b peaks vertical lines can be seen, when the electrons rearrange due to the magnetic eld. (c) Trace along a Coulom b peak in the QD conductance [dashed line in (a)]. The conductance oscillates over a wide magnetic eld range as demonstrated in the inset. (d) q detected by the QPC as a function of the magnetic eld along the dashed line in (b). For each of the light vertical lines a distinct step in q occurs.

to the gate voltage, where black m eans a large change in the conductance and white no change. For each C oulom b peak in the QD conductance, i.e. each change of electron number on the QD, a distinct peak in the derivative of the QPC conductance occurs. The signal shows the same e shape as the m easurem ent through the QD. But the QPC detector still works at low gate voltage, when the transport signal g_{QD} vanishes.

In the following we will analyze this behavior in more detail. In Fig. 3(a) (zoom of hatched box in Fig. 2) the typical zigzag caused by the shift of the dot-states in the magnetic eld can be clearly observed.

This behavior is explained as follows. In the shown range of the magnetic ekd, the spectrum of the QD consists of two Landau levels. The states of the nst (the outer) Landau level drop in energy with increasing magnetic ekd, the states in the second (the inner) Landau level rise. Therefore the energetically favorable state for an electron can be found alternately in the inner Landau level and in the outer Landau level. As a result electrons are redistributed with changing magnetic ekd and the C oulom b peaks shift upward in gate voltage, whenever the occupied state is in the inner Landau level and shifts dow nward in gate voltage whenever the occupied state is in the outer Landau level. This leads to the oscillating C oulom b peak position, as seen in 3(a).

M oreover, the conductance slightly di ers between two neighboring downward line segments. This can be explained by the appearance of spinblockade as discussed by C iorga et al. [13] and recently shown for LAO devices in [14].

In Fig. 3(c) a trace along a C oulom b peak [dashed line in Fig. 3(a)] is shown. It can clearly be seen, that the spin blockade pattern appears: the conductance along the C oulom b peak line shows an oscillating am plitude.

As the electrons on the QD are redistributed with increasing magnetic eld, a slight change of the effective charge measured by the QPC should be detectable. Therefore som e structure is expected between the Coulomb peaks. In Fig. 3(b) the QPC signal differentiated with respect to the magnetic eld is shown as a function of magnetic eld and gate voltage. The graph depicts the same parameter range as Fig. 3(a). Dark colors represent a decreasing QPC conductance, light colors an increasing conductance. Due to the zigzag pattern the Coulomb peak lines are segmented in black and white parts, as the charge on the QD alternates with rising magnetic eld for a xed applied gate voltage. Between the alm ost horizontal Coulom b lines additional nearly vertical lines are visible, that are weaker than the Coulomb peaks. They lead from the top of an upwardcusp in a Coulomb peak line to the bottom of the righthand nearest downward-cusp of the Coulomb peak line above. These lines are the result of the transition of a single electron, that is relocated from the inner Landau level to the outer Landau level. W e will refer to these lines as relocation lines in the following.

The QPC signal can be converted into an elective charge detected by the QPC. Therefore it is necessary to calibrate the detector. The easiest way is to use the C oulom b peak where the charge on the QD changes by one electron. In this way the horizontal shift of the QPC signal can be translated into a q, the change of the effective charge. Figure 3 (d) shows q along a cut through Fig. 3 (b) as indicated by the dashed line. Very distinct steps can be seen with a step height of 0.2 to 0.3 elective electron charges.

A simple picture explaining the charge rearrangement is given in Fig. 4. We assume that there are two main congurations of the QD called I and II. The circles show the inner (dark central part of the circles) and outer Landau shell (light ring) of the QD. The electrons occupying the two highest energy states are marked. In the con-

guration I both electrons occupy the inner shell. W ith rising magnetic eld the energy of the inner shell states increases. At some point it is energetically favorable for the spin up electron to move to the outer Landau shell. This situation is labled I! II. W hen the electron jumps to the outer shell, the potential of the QPC changes slightly. The change in the electron con guration changes the local potential of the QPC. This leads to a signi – cant change in the conductance of the QPC, which can be translated to a change of the electron constant. A fter

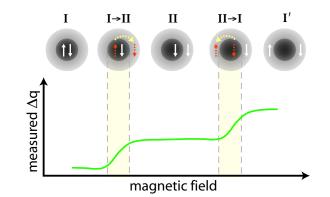


FIG. 4: Simple model for the charge redistribution. The spheres depict the inner and outer Landau shell and the two highest electron states on the QD for the di erent con gurations. Below the idealized QPC signal is shown. The conductance of the QPC slow by decreases due to the raising magnetic eld. At each electron transition from the inner to the outer shell a step occurs. Below this the measured charge is shown, as it can be calculated from the QPC signal.

the transition of the rst electron the QD reaches the con guration II. The detected charge stays constant until the second electron moves to the outer shell as shown in II! I. A gain the redistribution of an electron leads to an abrupt change in the QPC signal. A flerwards both electrons are in the outer shell. This state is called I' as it is equivalent to the beginning state.

W ith this simple model the position of the relocation lines in Fig. 3b can be understood. In Fig. 3(a,b,d) the con gurations I and II are labeled for exempli cation. Between the horizontal C oulom b peak lines no current

ow sthrough the Q D and the total charge stays constant, but the Q P C continues to detect the rearrangem ent of the electrons on the Q D. Transport m easurem ents through the Q D are limited to resonances with the leads, but the Q P C can be used to analyze the Q D structure even when current through the Q D is suppressed due to C oulom b blockade.

For other gate voltages, a rather di erent behavior can be observed. In Fig. 5 another $dg_{OPC} = dB$ plot is show n. In thism easurem ent the conductance of the QD is too low for direct transport m easurem ents. The tunnelling barriers to source and drain are tuned concurrently using the gates G1 and G2 to keep the coupling to source and drain symmetric. A gain the zigzag pattern can be seen for the two Coulom b peaks shown. Sim ilar to the m easurem ent presented in Fig. 3, transition lines are observed. As this form of the QD di ers from the con guration with asymmetric barriers shown in Fig. 3b the algebraic sign of the change in charge at the relocation line is di erent. Here the QPC detects an increasing e ective charge for each electron jumping to the outer shell. Slope and position of the lines are sim ilar to the results for asymmetric barriers but additional features can be seen: following each transition line an area of decreasing e ective charge appears. This area shows the opposite slope compared

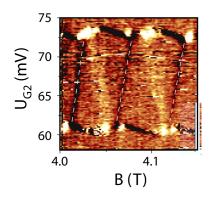


FIG.5: $dg_{QPC} = dB$ as a function of magnetic eld and gate voltage. Same type of measurement as presented in Fig. 3 (b) but for a symmetric coupling to source and drain and in a range, where the current though the QD is too low for direct measurement. A gain lines can be seen when an electron changes to the outer shell, white dashed lines are drawn as a guide to the eye. A dditional bright areas with an inverse slope occur between this lines.

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to the relocation lines and leads from an upward ank of the upper C oulom b peak line to an upward ank of the low er C oulom b peak line. The appearance of these areas can not be understood using the sim ple m odel presented above. It may result from a selfconsistent rearrangement of the charge inside the QD due to the in uence of the m agnetic eld.

In sum m ary we have perform ed transport m easurem ents on a quantum dot using a quantum point contact as a charge detector. By this we were able to extend the investigations to a regim e, that is unreachable by transport m easurem ents. We analyzed the QD's behavior in high m agnetic elds. We used the QPC to observe the QD electron con guration while C oulom b blockade suppresses transport. By this we were able to detect in a non-invasive way the rearrangem ent of electrons in the QD due to the m agnetic eld. We analyzed these rearrangem ent for a constant num ber of electrons, where only the internal charge con guration changes. We presented a sim ple m odel to explain the experim ental data and have shown results that need further discussion.

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